




Material Characterization and Modeling for Microchip Encapsulation Simulation

STMicroelectronics
Daniela Spini

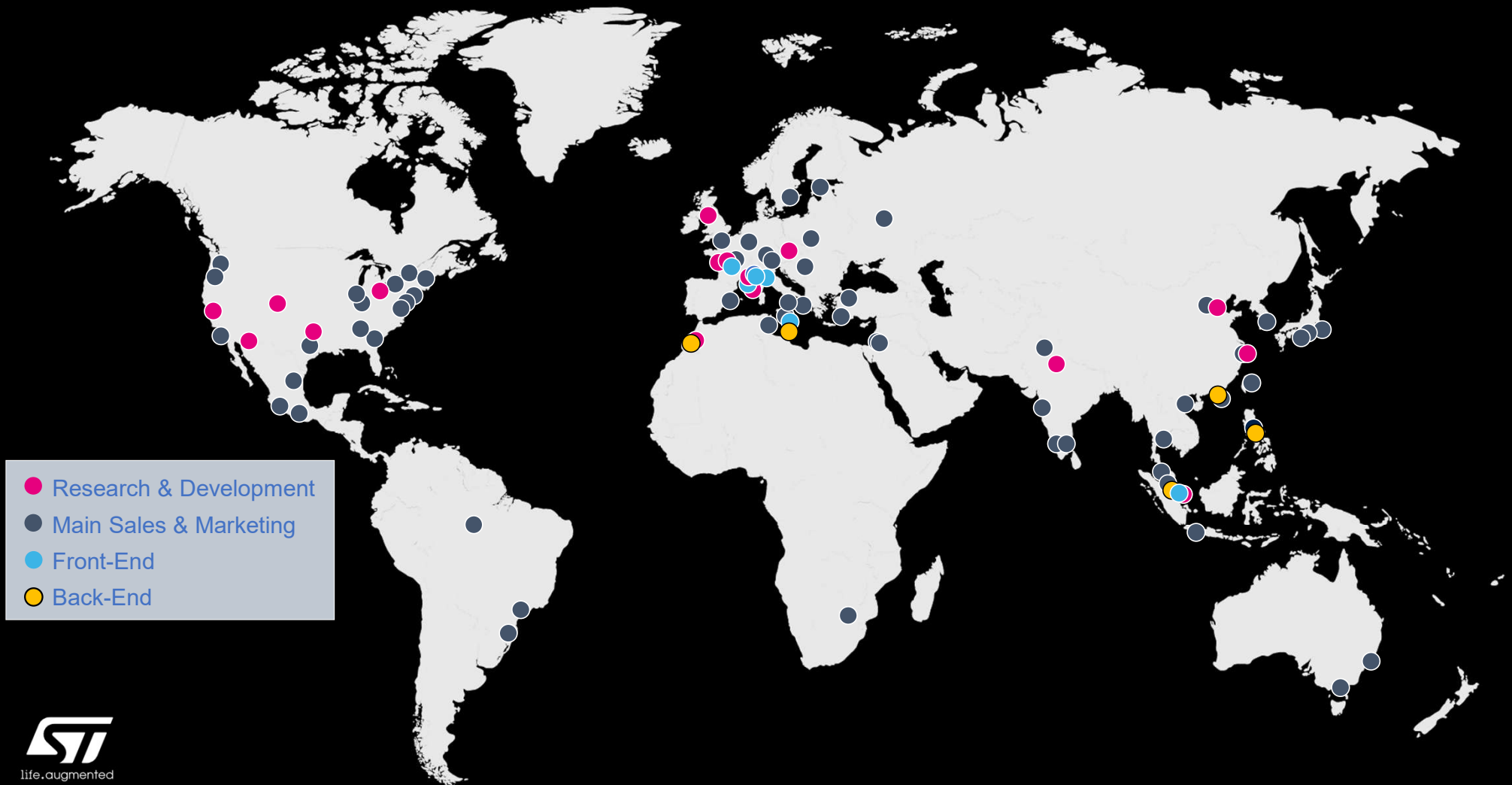
Moldex3D

An abstract, flowing graphic in shades of blue, purple, and magenta, resembling liquid or smoke, positioned at the bottom of the slide.

- 
- . Introduction of STMicroelectronics
 - . IC Packaging
 - . Material Characterization
 - . Chip Encapsulation with Moldex3D
 - . Outcome

STMicroelectronics: Beyond Semiconductor

STMicroelectronics worldwide



Our technology stems from long-term strategic enablers

Smart Mobility



ST provides innovative solutions to help our customers make driving **safer, greener and more connected** for everyone

Power & Energy



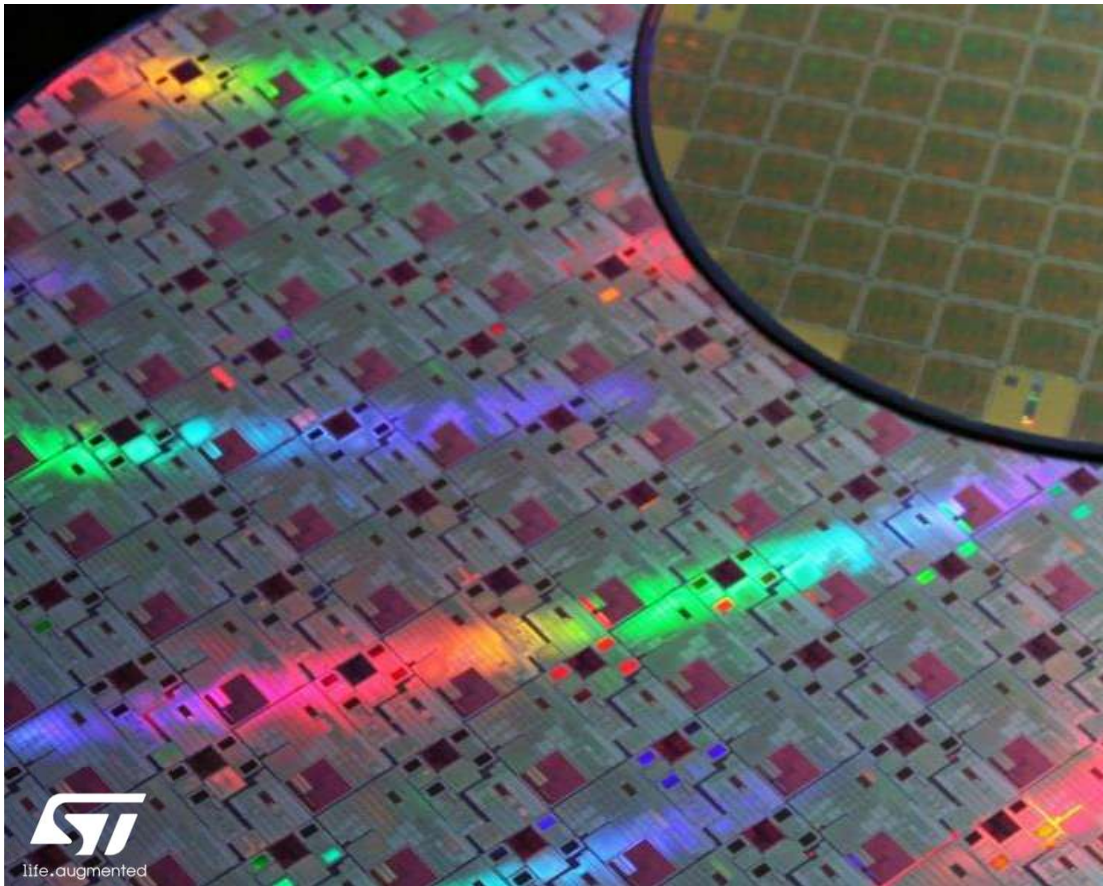
ST technology and solutions enable customers to increase **energy efficiency** everywhere and support the use of renewable energy sources

Internet of Things & 5G



ST provides **sensors, embedded processing solutions, connectivity, security and power management**, as well as **tools and ecosystems** to make development fast and easy for our customers

Semiconductor technologies are our foundation



Dedicated
Automotive ICs



Analog, Industrial &
Power Conversion ICs



GP MCU & MPU,
Secure MCUs



Discrete &
Power Transistors



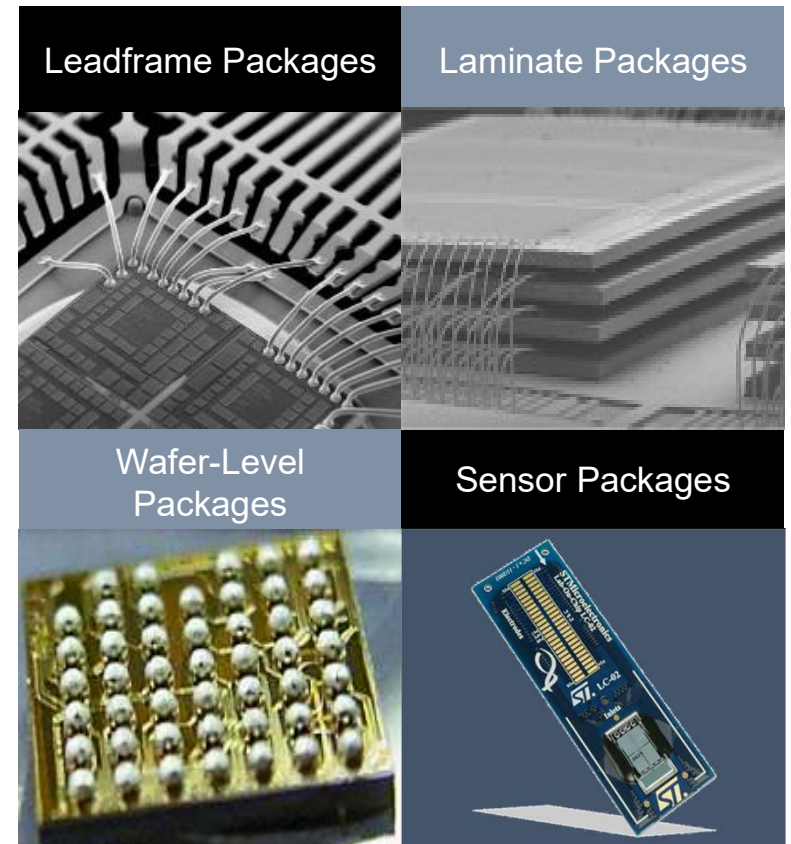
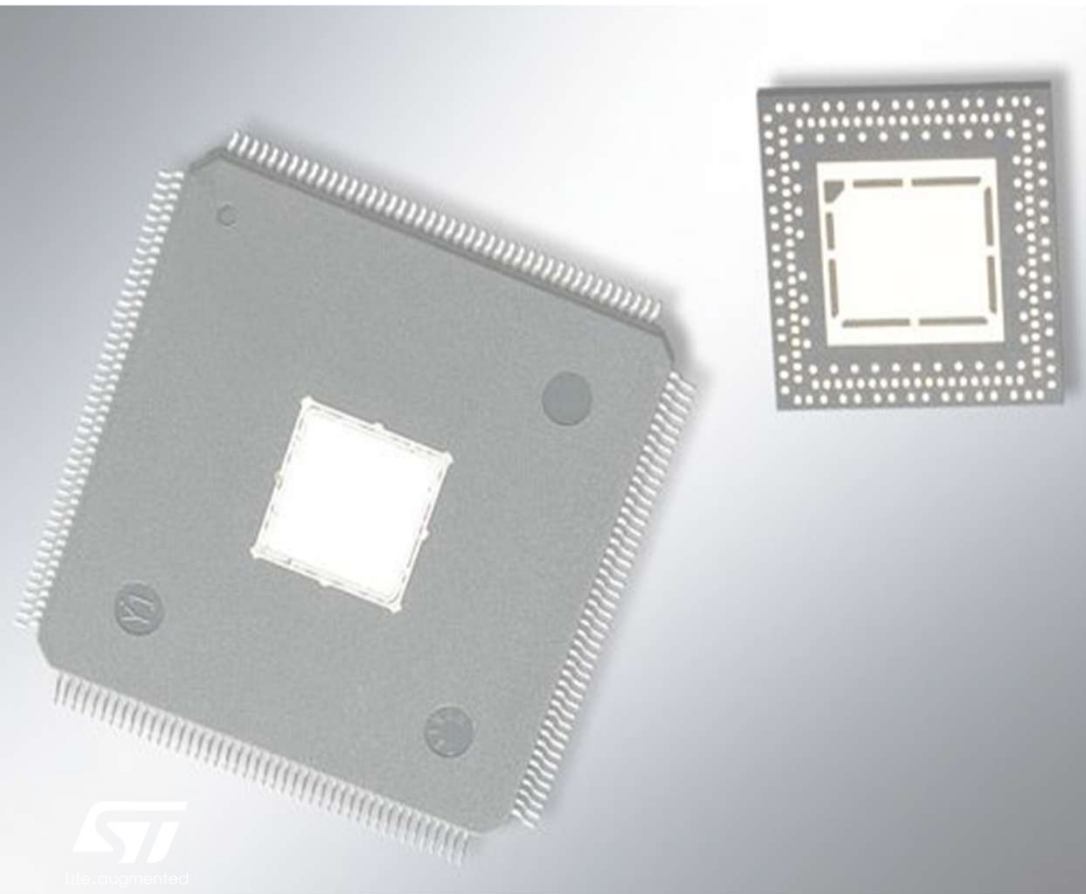
MEMS & Optical
sensing solutions



ASICs based on ST
technologies

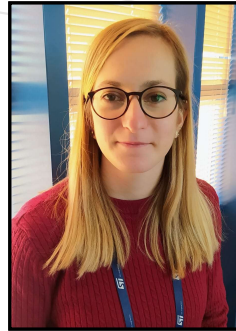


Packaging technologies are our future



About myself

Italy
(Agrate Brianza)



- Modeling and Characterization Engineer
- Advanced laboratory experiments on materials for IC packaging
- Molding process modeling for R&D activity
- MSc in Material and Nanotechnology Engineering

IC Packaging

What's a package in microelectronics?

An added cost

A piece of plastic

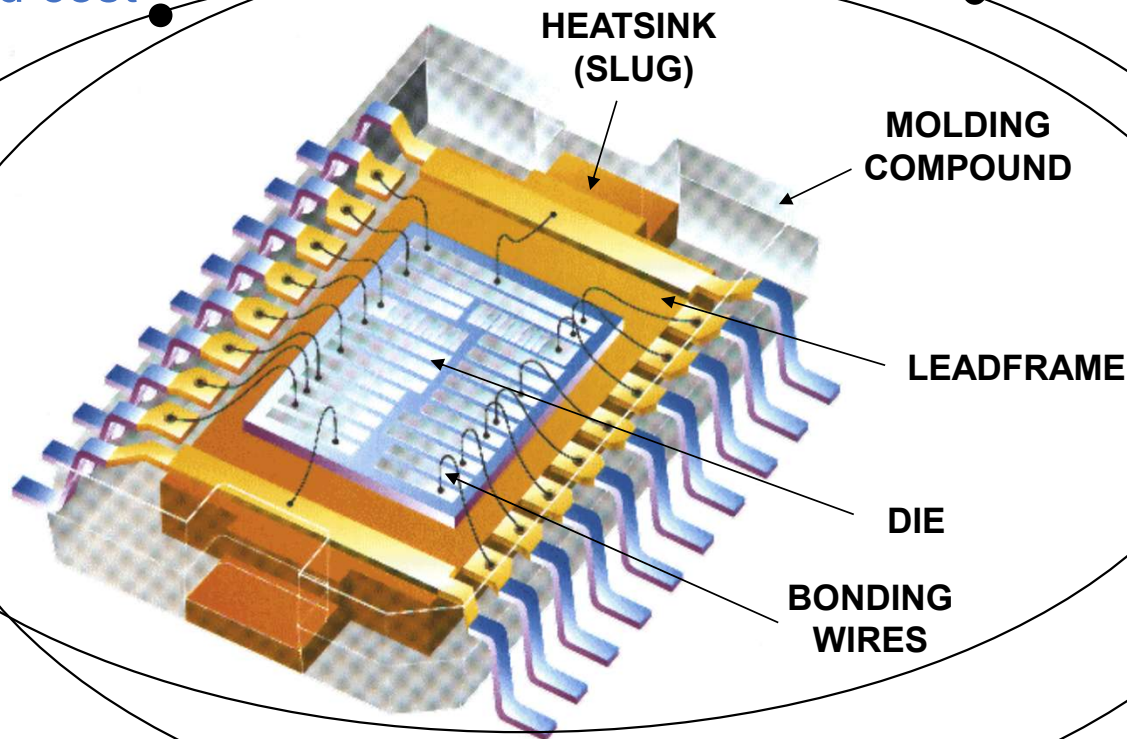
A technology

A system

An electrical
interconnection

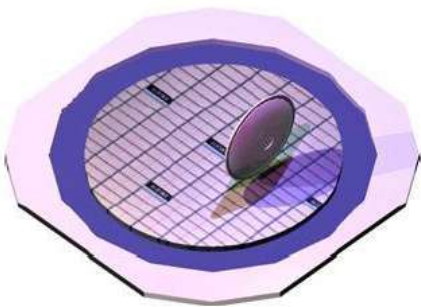
A problem

A protection

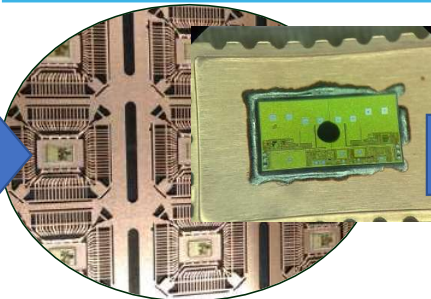


Packaging assembly process flow

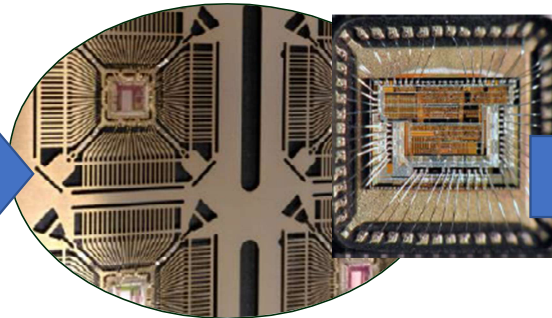
Wafer sawing



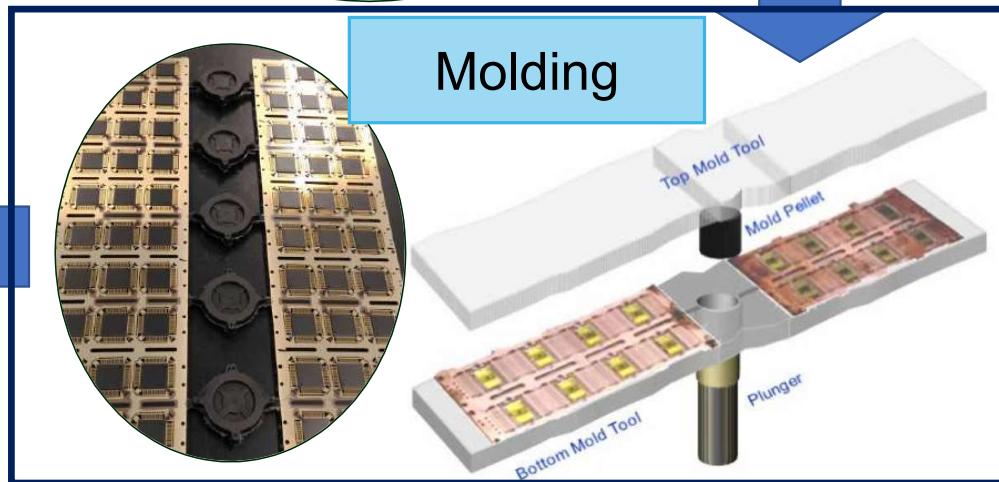
Die attach on
leadframe



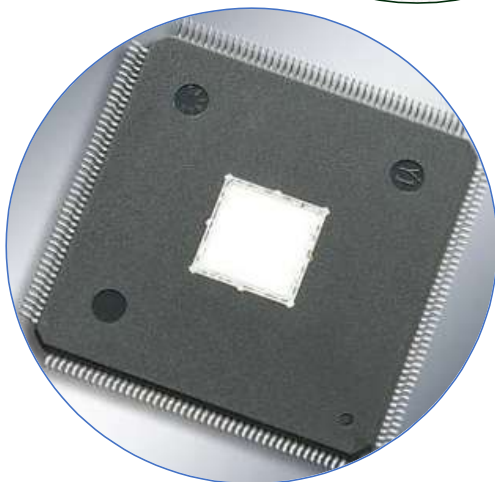
Wire bonding



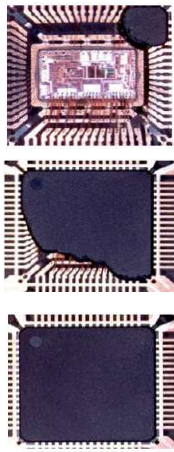
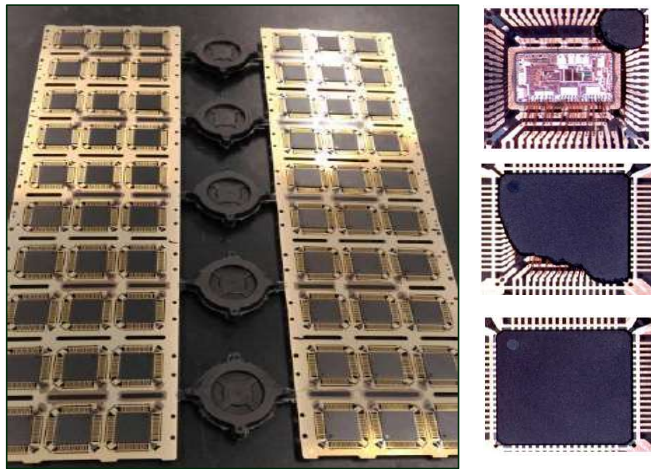
Molding



Final
product



Molding process

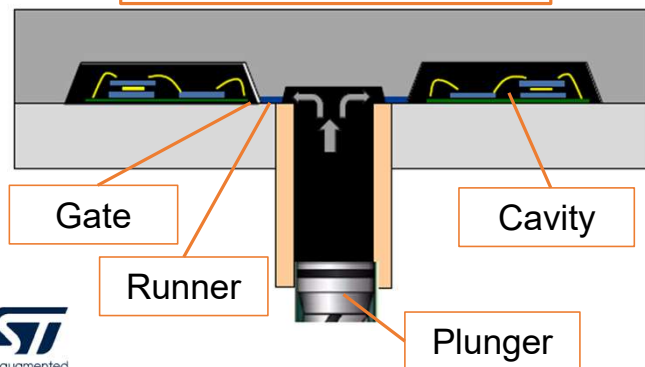


- Molding is the process of microchip encapsulation within a mold cavity by epoxy molding compound (EMC) injection
- EMC is a combination of organic (thermoset polymer) and inorganic (silica filler)

What does EMC provide?

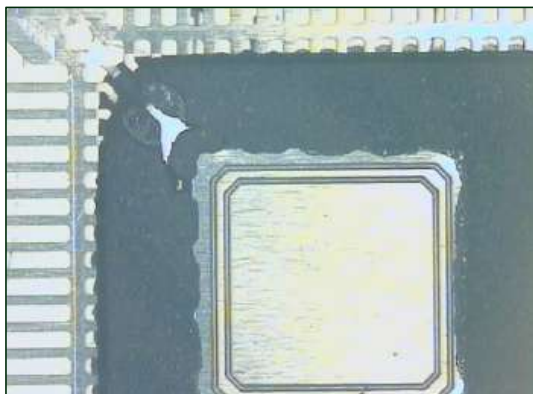
- Protection of the die from any damage and contamination
- Package structural and mechanical stability
- Create a barrier to limit the corrosion
- Low-cost manufacturing

Transfer molding

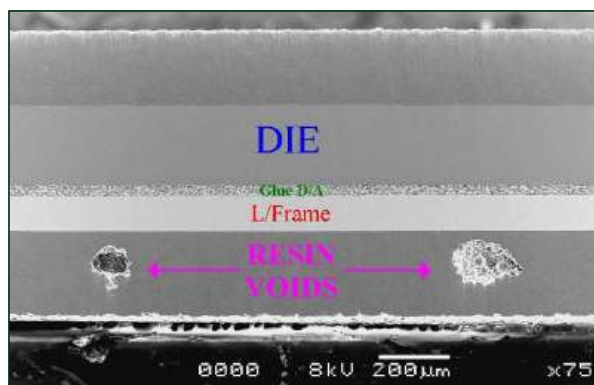


Molding process

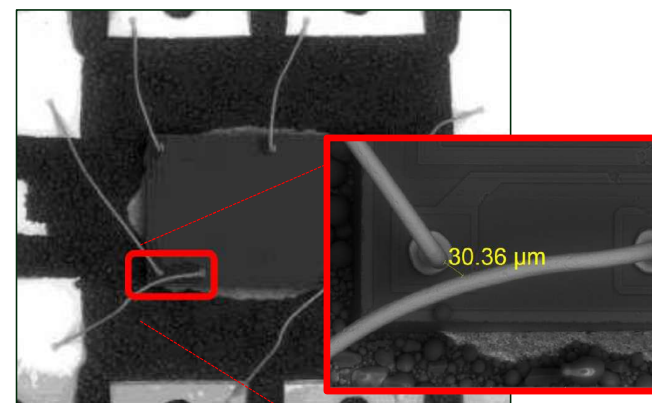
Typical reliability issues caused by molding process which led to production loss and/or customer complaint



Incomplete filling



Internal voids



Wire sweeping and crossing

It's time to predict molding defects by acting on:

- Process parameters
- Material properties
- Leadframe/cavity design

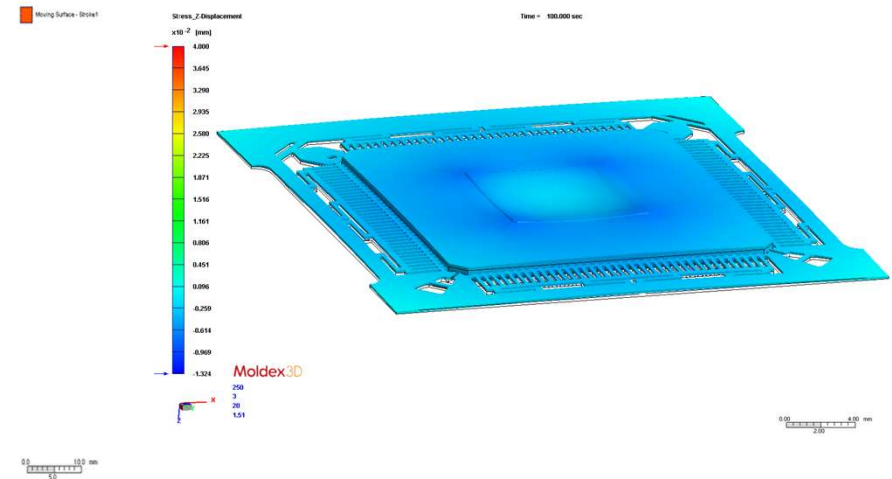
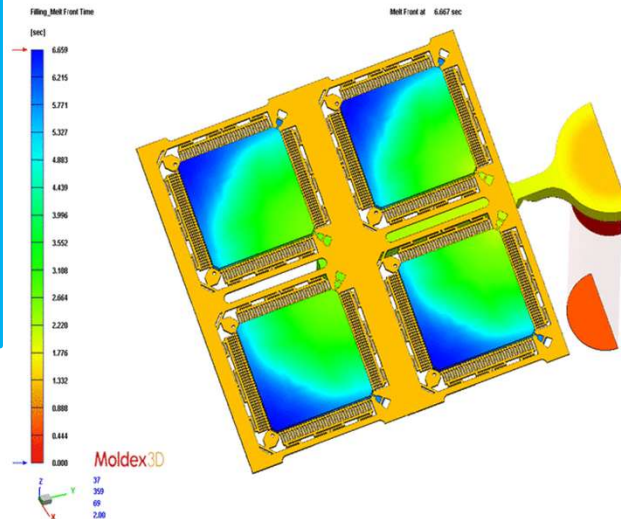
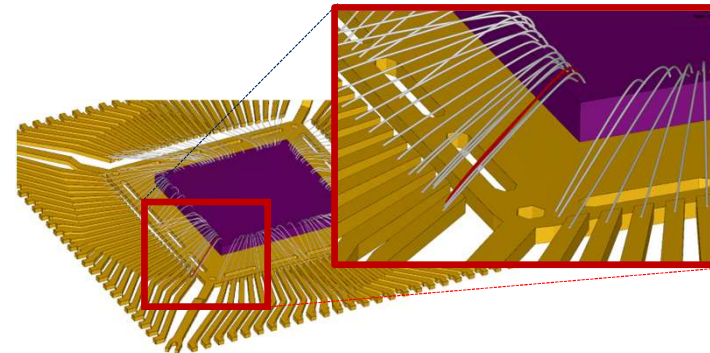
Modeling with
Moldex3D
IC Packaging

Moldex3D IC Packaging

- Simulation of the process of chip encapsulation with EMC from leadframe to chip, including wire bonding
- The process is relatively important for the advance variation of filling, curing phenomenon simulation, and further warpage

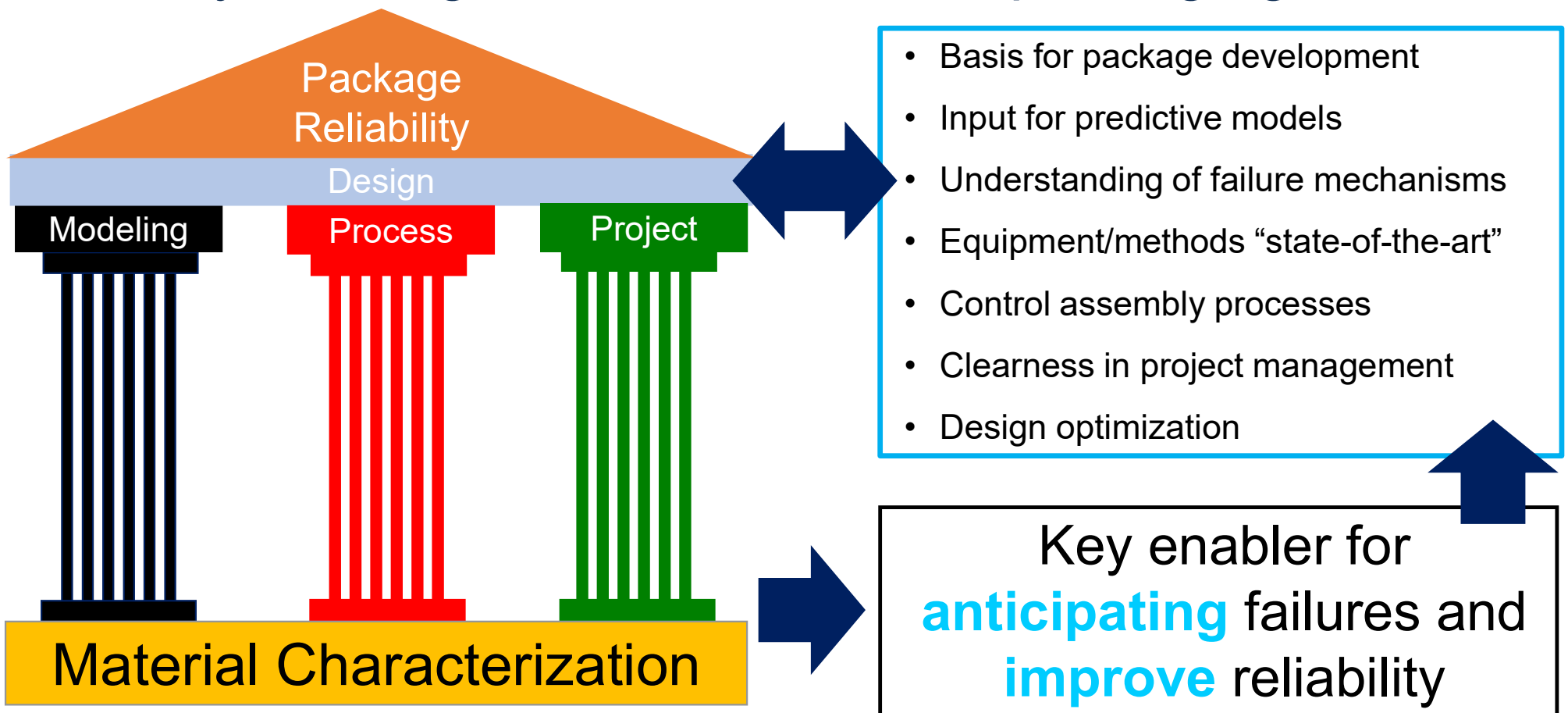
Challenges:

- Incomplete filling
- Wire sweep
- Paddle shift
- Warpage



Material Characterization

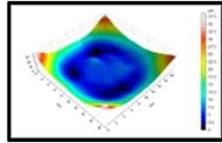
Why investigate materials for IC packaging?



How we do material characterization?

- Characterization of packaging materials
 - Thermal
 - Thermo-mechanical
 - Rheological
 - Morphological

Dynamic Warpage



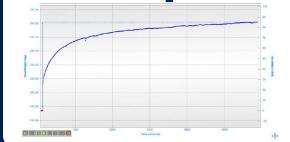
Mechanical Testing



Thermal Analysis

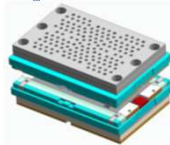


Humidity Absorption

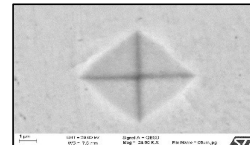


Material Laboratory

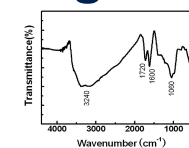
Sample Preparation



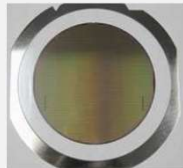
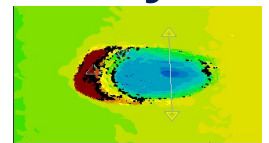
Material Hardness



Material Recognition

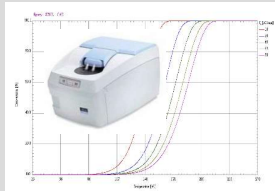


Surface Analysis

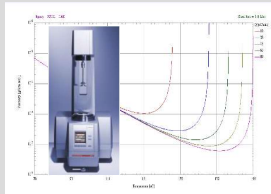


From resin characterization to Moldex3D

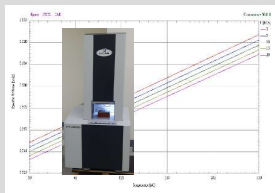
RHEOLOGY



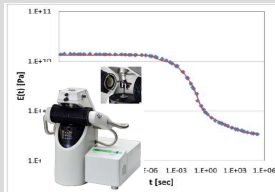
Curing kinetics
(R)



Viscosity
(τ , u)



P-V-T-C
(V , T , p)



Visco-
elasticity (E)



CONTINUUM

Thermal
conductivity (k)



Heat capacity
(C_p)



Thermal expansion
(CTE, T_g)



MODELING

Mass balance

$$\frac{\partial \rho}{\partial t} + \nabla \cdot (\rho \mathbf{u}) = 0$$

Momentum balance

$$\rho \frac{D\mathbf{u}}{Dt} = \nabla \cdot \boldsymbol{\tau} - \nabla p + \rho \mathbf{g}$$

Energy balance

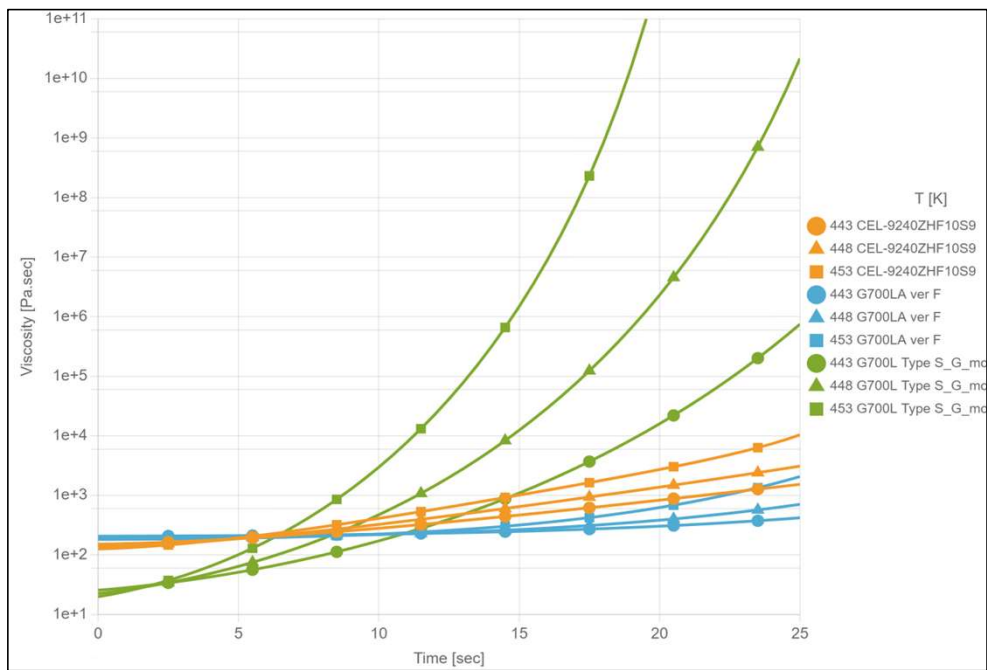
$$\rho C_p \left(\frac{\partial T}{\partial t} + \mathbf{u} \cdot \nabla T \right) = \nabla \cdot k \nabla T - \boldsymbol{\tau} : \dot{\boldsymbol{\gamma}} + S$$

Thermoset conversion balance

$$\dot{X} + \nabla \cdot \mathbf{j} + R = 0$$

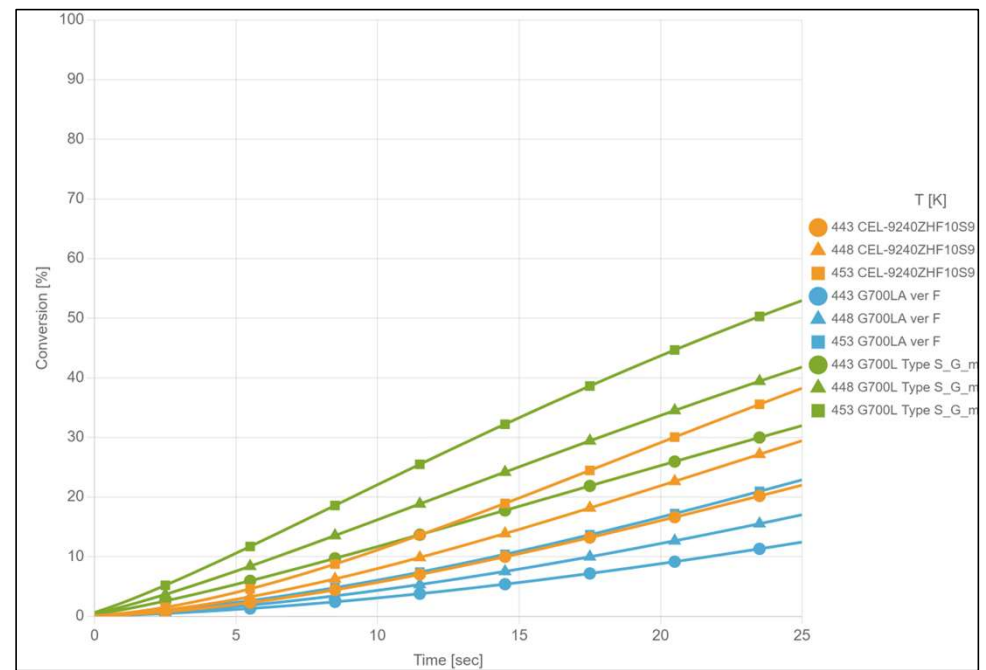
Moldex3D material models

Viscosity



Process window for EMC filling

Curing kinetics

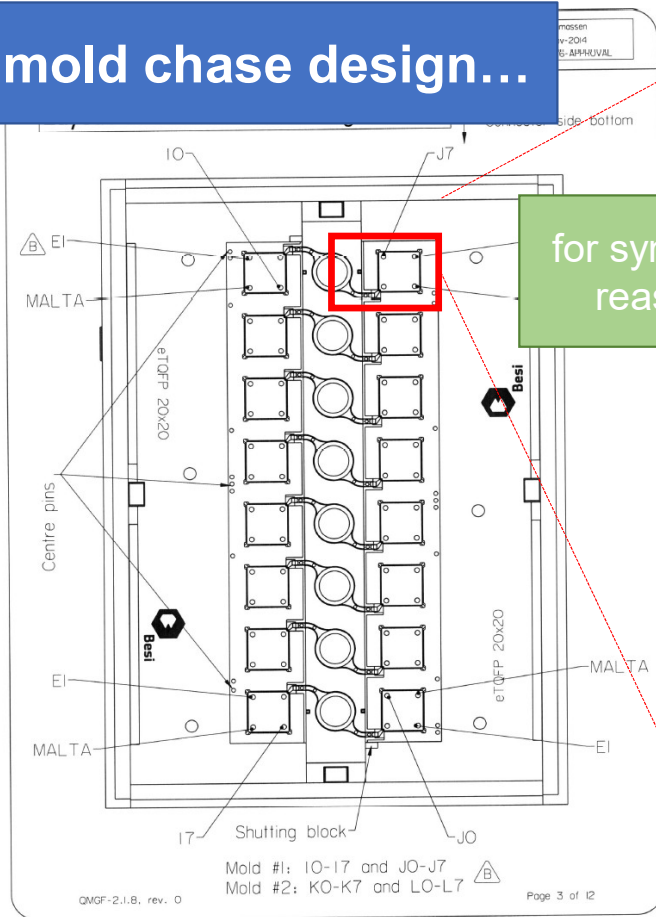


Degree of polymerization of EMC

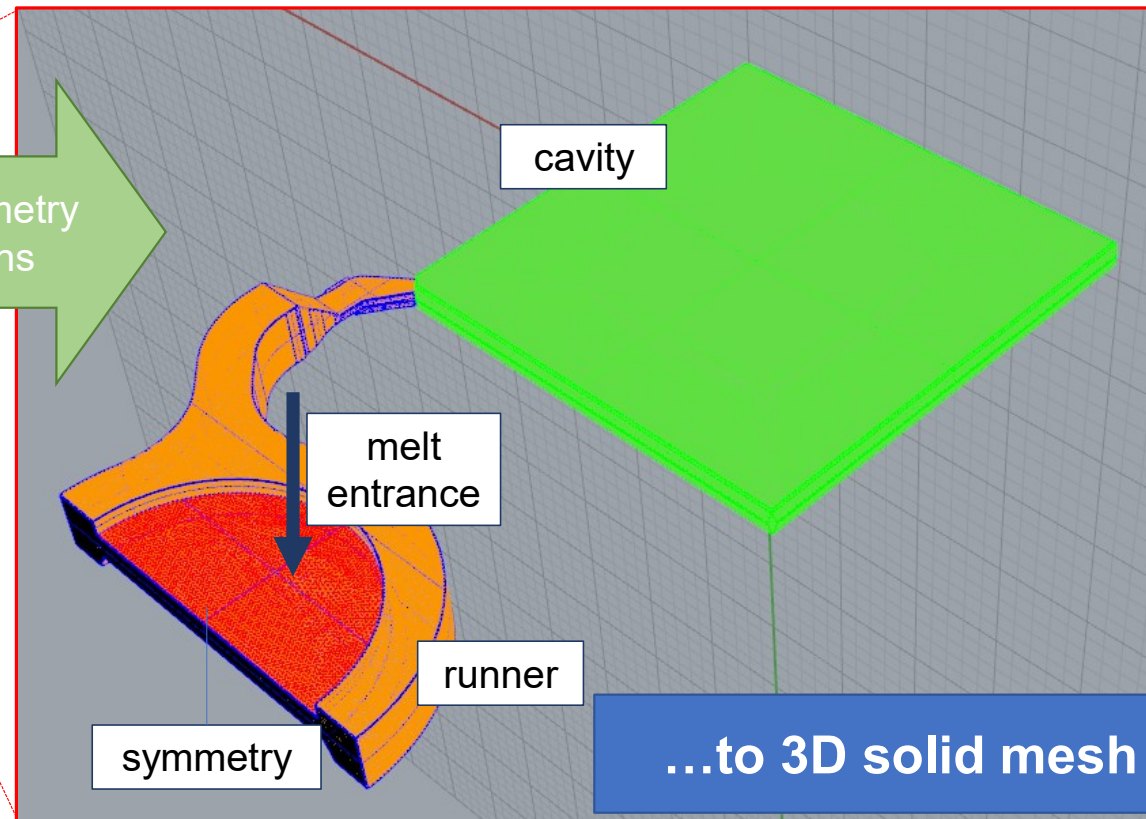
Chip Encapsulation with Moldex3D

Need for 3D model

From mold chase design...



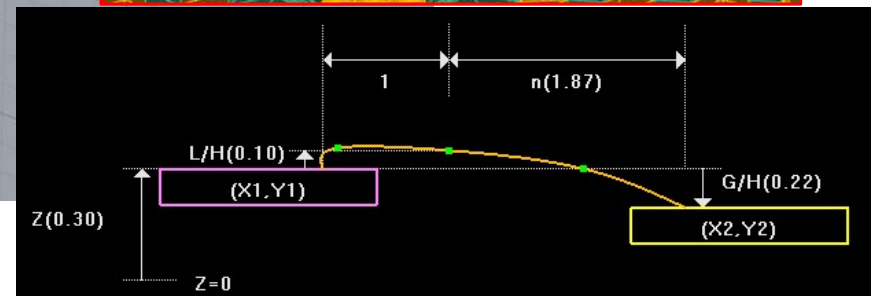
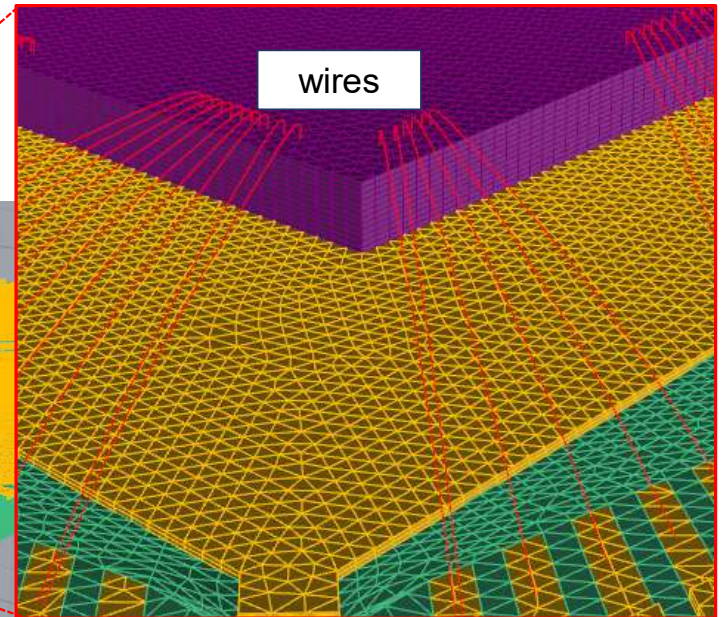
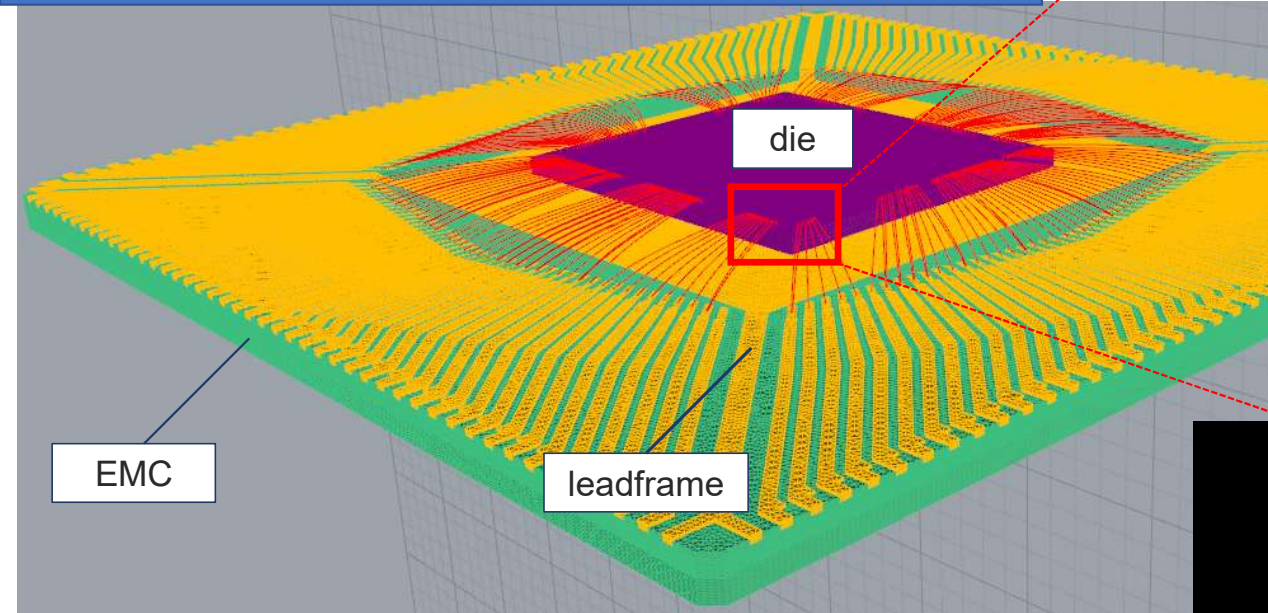
for symmetry
reasons



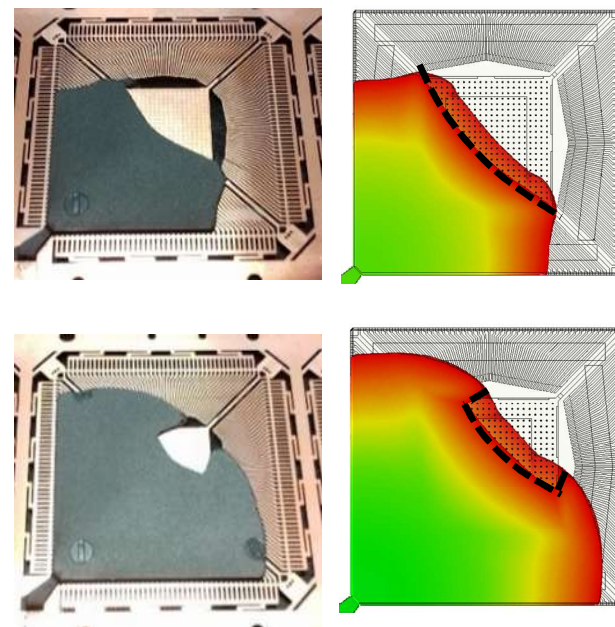
...to 3D solid mesh

Need for 3D model

Solid mesh details and wire bonding

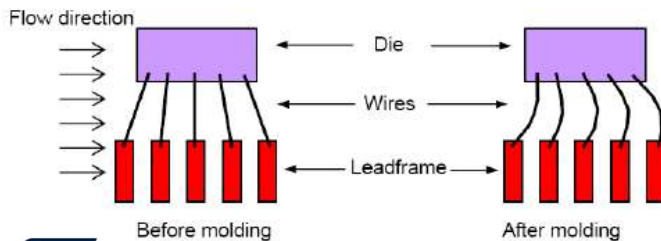
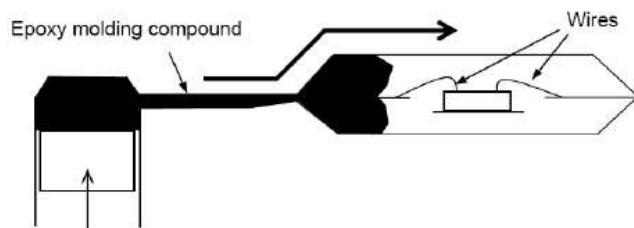
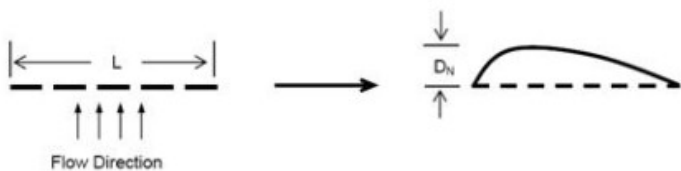


- Model validation by comparison with short shot experiments



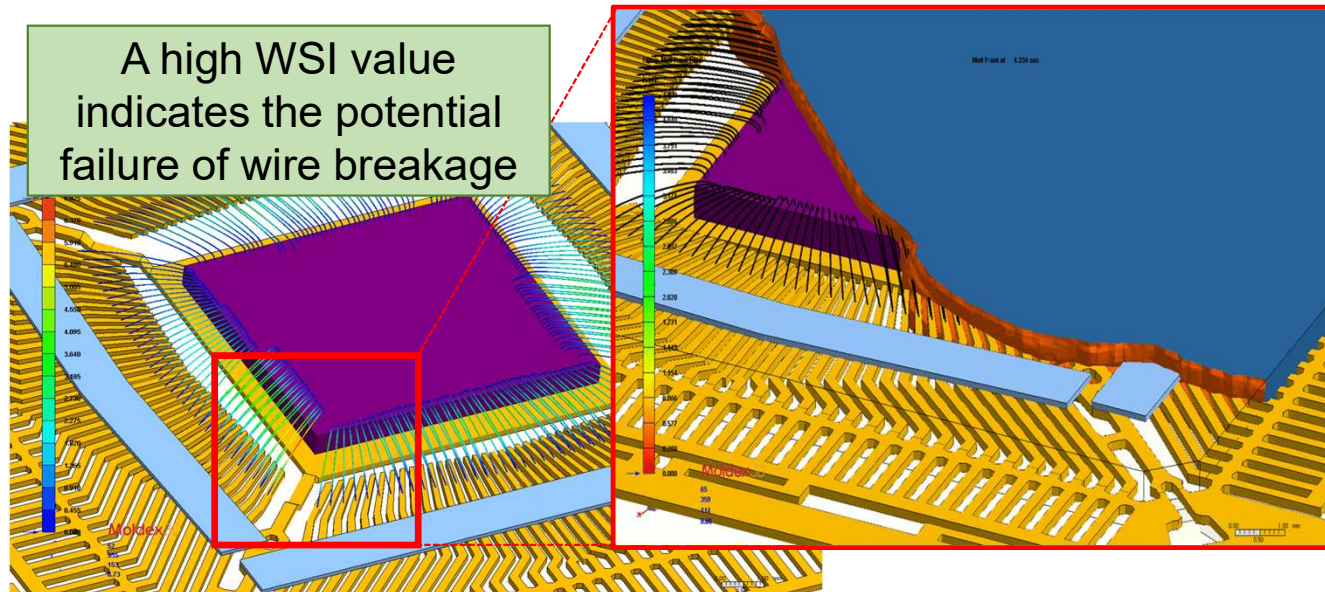
What's happening to wires?

$$\text{Wire Sweep Index (\%)} \equiv D_N / L$$



- Efficient prediction of the excessive amount of wires deformation during EMC flow
- Significant indicator of wire structure optimization (wire sweeping index – WSI)

A high WSI value indicates the potential failure of wire breakage



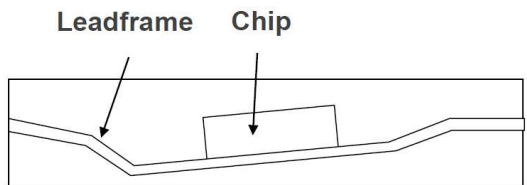
Is die pad tilting?

- Reproduction of die pad tilt effect due to unbalanced pressure loading from EMC flow during encapsulation
- Interaction between fluid and structure during EMC filling analysis

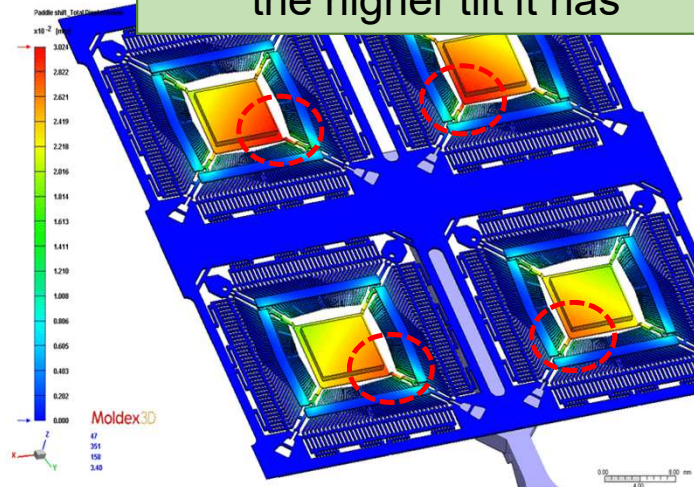
Unbalanced pressure loading from EMC flow



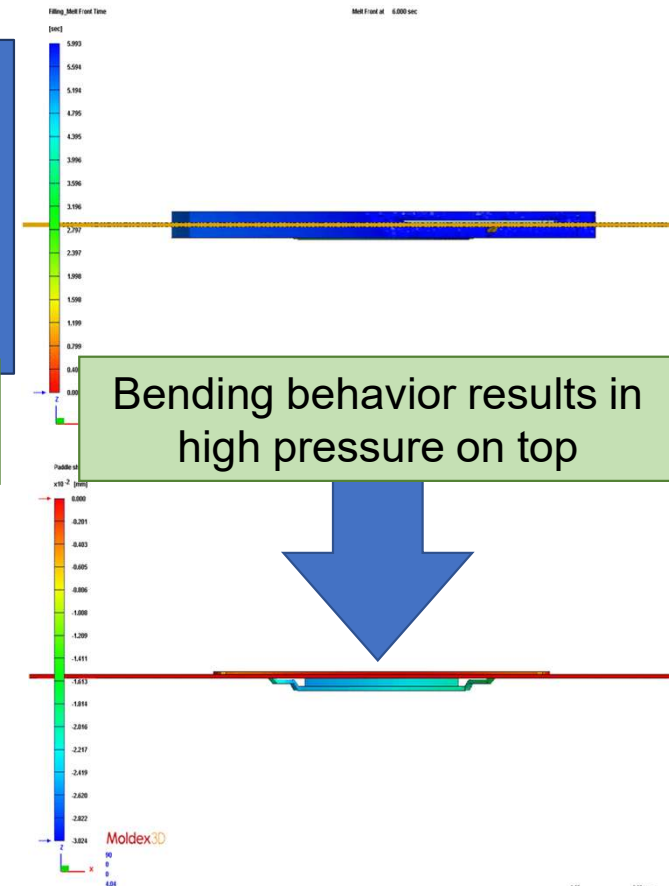
(a) Before deflection



(b) After deflection



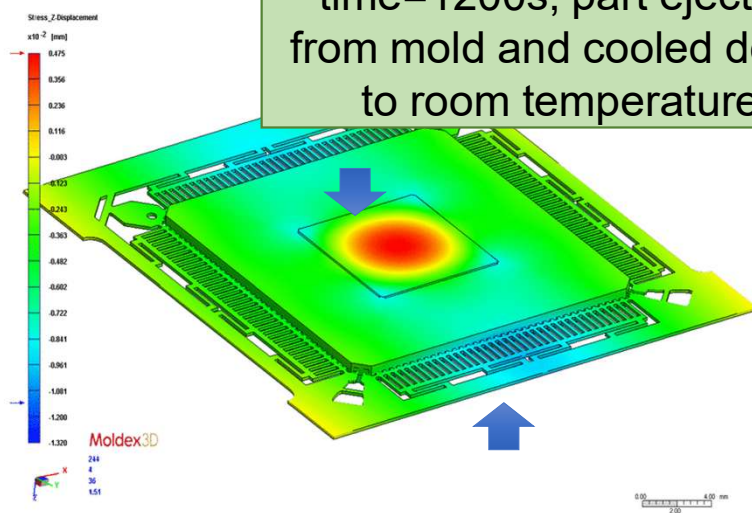
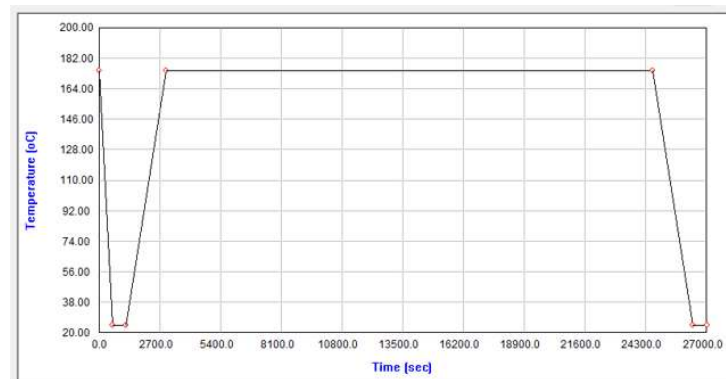
The closer to the gate area,
the higher tilt it has



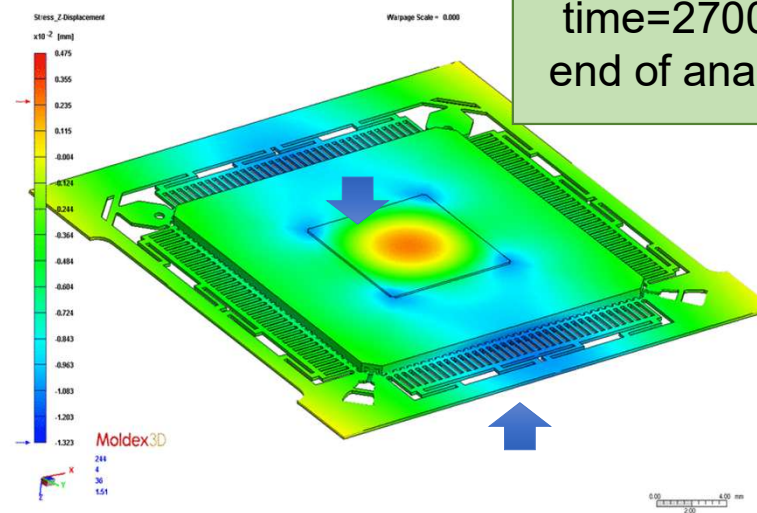
Bending behavior results in
high pressure on top

What about deformation?

- Reproduction of warpage in different steps for package warpage validation in IC encapsulation process:
 - After in-mold curing
 - After post mold curing condition



time=1200s, part ejected from mold and cooled down to room temperature



time=27000s, end of analysis

Workflow

Geometry Modeling

Moldex3D Mesh

Geometry solid mesh

Attribute setting

Wire setting / B.C.

Export solid model

Simulation: Moldex3D IC Packaging

Filling

Curing

Warpage

Filling drag force

Temperature conversion

Pressure distribution

Stress analysis

Mechanical properties

Viscosity

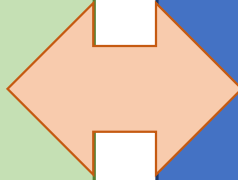
Paddle deflection

Wire deformation

Outcome

Outcome

- Material characterization has a key role in IC package development
- Experimental activity on package materials
- EMC characterization
 - ✓ Thermal
 - ✓ Thermo-mechanical
 - ✓ Rheological



- Chip encapsulation with Moldex3D
- Modeling activity requires strong knowledge of EMC properties in order to better reproduce:
 - ✓ EMC filling behavior
 - ✓ Wire deformation during encapsulation
 - ✓ Paddle shift cause by unbalanced flow
 - ✓ Warpage during post mold curing

Anticipation of process flow
Improvement of package reliability

Thank you

